

#### Is Now Part of



# ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <a href="https://www.onsemi.com">www.onsemi.com</a>

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA Class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, emplo



**April 2013** 

### FDT3N40

# N-Channel UniFET<sup>™</sup> MOSFET 400 V, 2.0 A, 3.4

#### **Features**

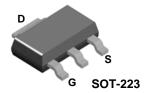
- $R_{DS(on)} = 3.4 \Omega \text{ (Max.)} @ V_{GS} = 10 \text{ V}, I_D = 1.0 \text{ A}$
- Low Gate Charge (Typ. 4.5 nC)
- Low Crss (Typ. 3.7 pF)
- 100% Avalanche Tested

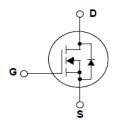
#### **Applications**

- LCD/LED TV
- Lighting
- Uninterruptible Power Supply

## **Description**

UniFET™ MOSFET is Fairchild Semiconductor®'s high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.





#### **Absolute Maximum Ratings**

Symbol	Parameter			FDT3N40	Unit
V <sub>DSS</sub>	Drain-Source Voltage			400	V
I <sub>D</sub>	Drain Current	- Continuous (T <sub>C</sub> = 25 - Continuous (T <sub>C</sub> = 10		2.0 * 1.2 *	A A
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	8.0 *	А
V <sub>GSS</sub>	Gate-Source voltage			±30	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy		(Note 2)	46	mJ
I <sub>AR</sub>	Avalanche Current		(Note 1) 2		A
E <sub>AR</sub>	Repetitive Avalanche Energy		(Note 1)	0.2	mJ
dv/dt	Peak Diode Recover	y dv/dt	(Note 3)	4.5	V/ns
P <sub>D</sub>	Power Dissipation (T <sub>C</sub> = 25°C) - Derate above 25°C			2 0.02	W W/°C
T <sub>J,</sub> T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +150	°C
T <sub>L</sub>	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds		urpose,	300	°C

<sup>\*</sup> Drain current limited by maximum junction temperature

#### Thermal Characteristics

Symbol	Parameter	FDT3N40	Unit
$R_{ heta JA}^{ *}$	Thermal Resistance, Case-to-Sink Typ.	60	°C/W

<sup>\*</sup> Surface Mounted on JESD51-3 Board, T<0.1sec.

# **Package Marking and Ordering Information**

<b>Device Marking</b>	Device	Package	Reel Size	Tape Width	Quantity
FDT3N40	FDT3N40TF	SOT-223	330mm	12mm	4000

# **Electrical Characteristics** $T_C = 25$ °C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max	Unit		
Off Charac	Off Characteristics							
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_{D} = 250\mu A$	400			V		
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	I <sub>D</sub> = 250μA, Referenced to 25°C		0.4		V/°C		
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 400V, V <sub>GS</sub> = 0V V <sub>DS</sub> = 320V, T <sub>C</sub> = 125°C			1 10	μA μA		
I <sub>GSSF</sub>	Gate-Body Leakage Current, Forward	V <sub>GS</sub> = 30V, V <sub>DS</sub> = 0V			100	nA		
I <sub>GSSR</sub>	Gate-Body Leakage Current, Reverse	$V_{GS} = -30V$ , $V_{DS} = 0V$			-100	nA		
On Charac	On Characteristics							
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		5.0	V		
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> = 10V, I <sub>D</sub> = 1A		2.8	3.4	Ω		
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = 40V$ , $I_D = 1A$ (Note 4)		2		S		
Dynamic C	Dynamic Characteristics							
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V,		173	225	pF		
C <sub>oss</sub>	Output Capacitance	f = 1.0MHz		30	40	pF		
C <sub>rss</sub>	Reverse Transfer Capacitance			3.7	6	pF		
Switching	Characteristics							
t <sub>d(on)</sub>	Turn-On Delay Time	$V_{DD} = 200V, I_{D} = 2A$		10	30	ns		
t <sub>r</sub>	Turn-On Rise Time	$R_G = 25\Omega$		30	70	ns		
t <sub>d(off)</sub>	Turn-Off Delay Time			10	30	ns		
t <sub>f</sub>	Turn-Off Fall Time	(Note 4, 5)		25	60	ns		
Qg	Total Gate Charge	V <sub>DS</sub> = 320V, I <sub>D</sub> = 2A		4.5	6	nC		
$Q_{gs}$	Gate-Source Charge	V <sub>GS</sub> = 10V		1.2		nC		
$Q_{gd}$	Gate-Drain Charge	(Note 4, 5)		2		nC		
Drain-Source Diode Characteristics and Maximum Ratings								
I <sub>S</sub>	Maximum Continuous Drain-Source Diode Forward Current				2	Α		
I <sub>SM</sub>	Maximum Pulsed Drain-Source Diode Forward Current				8	Α		
$V_{SD}$	Drain-Source Diode Forward Voltage	V <sub>GS</sub> = 0V, I <sub>S</sub> = 2A			1.4	V		
t <sub>rr</sub>	Reverse Recovery Time	$V_{GS} = 0V$ , $I_S = 2A$		210		ns		
Q <sub>rr</sub>	Reverse Recovery Charge	$dI_F/dt = 100A/\mu s   (Note 4)$		0.75		μС		

#### NOTES

<sup>1.</sup> Repetitive Rating: Pulse width limited by maximum junction temperature

<sup>2.</sup> L = 10mH, I  $_{AS}$  = 2A, V  $_{DD}$  = 50V, R  $_{G}$  = 25 $\Omega$ , Starting T  $_{J}$  = 25°C

<sup>3.</sup> I\_{SD}  $\leq$  2A, di/dt  $\leq$  200A/µs, V\_{DD}  $\leq$  BV\_DSS, Starting T\_J = 25°C

<sup>4.</sup> Pulse Test: Pulse width  $\leq 300 \mu \text{s}, \ \text{Duty Cycle} \leq 2\%$ 

 $<sup>{\</sup>bf 5.} \ {\bf Essentially} \ {\bf Independent} \ {\bf of} \ {\bf Operating} \ {\bf Temperature} \ {\bf Typical} \ {\bf Characteristics}$ 

# **Typical Performance Characteristics**

Figure 1. On-Region Characteristics

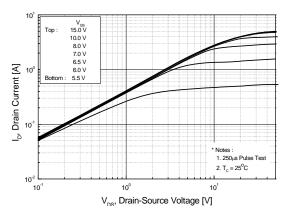


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

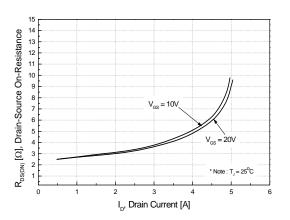


Figure 5. Capacitance Characteristics

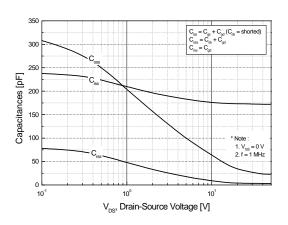


Figure 2. Transfer Characteristics

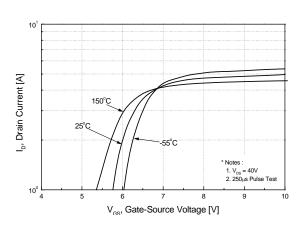
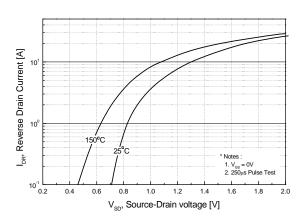
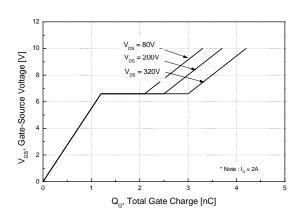


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperatue



**Figure 6. Gate Charge Characteristics** 



# **Typical Performance Characteristics** (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

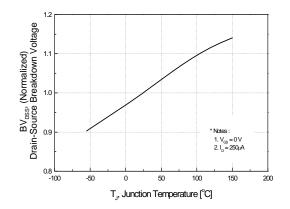


Figure 8. On-Resistance Variation vs. Temperature

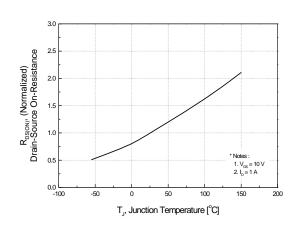
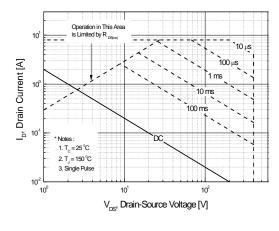


Figure 9. Maximum Safe Operating Area

Figure 10. Maximum Drain Current vs. Case Temperature



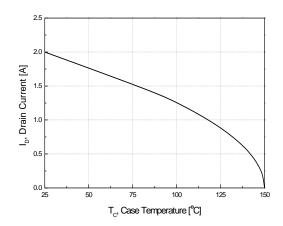
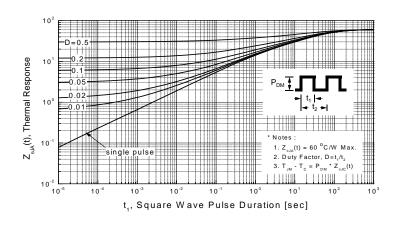
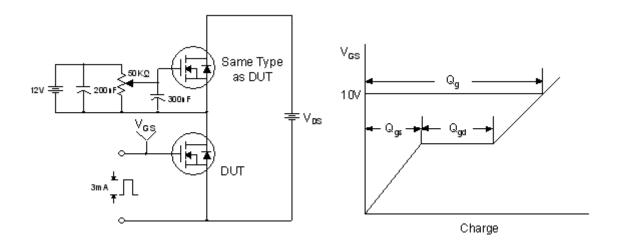


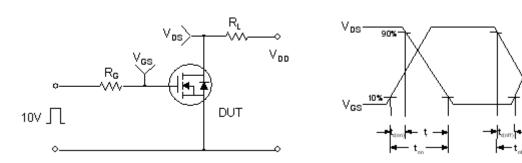
Figure 11. Transient Thermal Response Curve



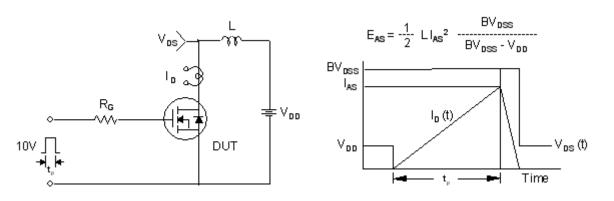
#### **Gate Charge Test Circuit & Waveform**



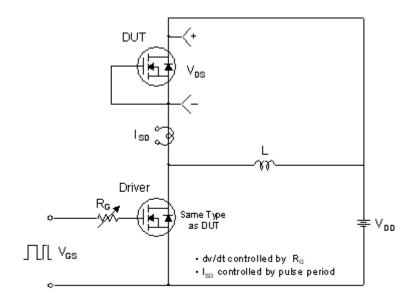
#### **Resistive Switching Test Circuit & Waveforms**

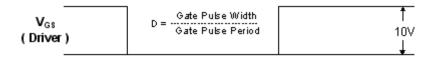


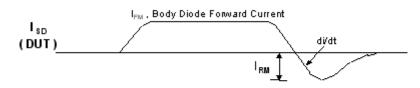
#### **Unclamped Inductive Switching Test Circuit & Waveforms**

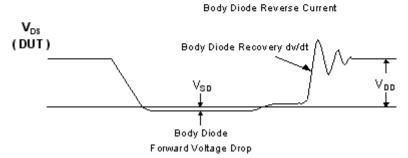


#### Peak Diode Recovery dv/dt Test Circuit & Waveforms



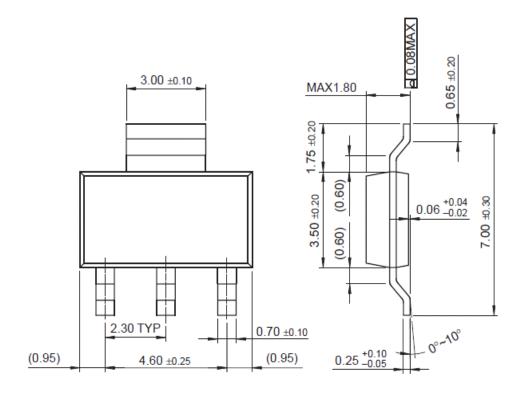


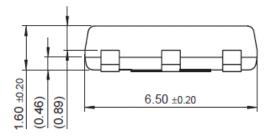




#### **Mechanical Dimensions**

# SOT-223









#### **TRADEMARKS**

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

(1)<sub>®</sub>

2Cool™ FPS™ AccuPower™ AX-CAP®\* F-PFS™  $\widehat{\mathsf{FRFET}^{@}}$ 

BitSiC™ Global Power Resource<sup>SM</sup> Build it Now™ Green Bridge™ CorePLUS™ Green FPS™

CorePOWER™ Green FPS™ e-Series™ CROSSVOLT™ Gmax™

CTL™ GTO™ Current Transfer Logic™ IntelliMAX™ DEUXPEED® ISOPLANAR™

Dual Cool™ Marking Small Speakers Sound Louder EcoSPARK®

MegaBuck™ EfficentMax™ MICROCOUPLER™ ESBC™ MicroFET™

MicroPak™ MicroPak2™ Fairchild<sup>®</sup> MillerDrive™ Fairchild Semiconductor® MotionMax™ FACT Quiet Series™ mWSaver™ FACT<sup>®</sup> FAST® OptoHiT™ OPTOLOGIC® FastvCore™ **OPTOPLANAR®**  PowerTrench® PowerXS™ Programmable Active Droop™

 $QS^{TM}$ Quiet Series™ RapidConfigure™

Saving our world, 1mW/W/kW at a time™

SignalWise™ SmartMax™ SMART START™

Solutions for Your Success™

STEALTH™ SuperFET® SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS® SyncFET™

Svnc-Lock™

SYSTEM®' TinvBoost<sup>T</sup> TinyBuck™ TinyCalc™ TinyLogic<sup>®</sup> TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TranSiC<sup>®</sup> TriFault Detect™ TRUECURRENT®\*

**UHC®** Ultra FRFET™ UniFET™ VCX<sup>TM</sup>

uSerDes™

VisualMax™ VoltagePlus™ XS™

\*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

FETBench™

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY
FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or

#### ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

#### PRODUCT STATUS DEFINITIONS **Definition of Terms**

Datasheet Identification Product Status		Definition		
Advance Information Formative / In Design		Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed Full Production		Datasheet contains final specifications. Fairchild Semiconductor reserves the right make changes at any time without notice to improve the design.		
Obsolete Not In Production		Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

Rev. 164

ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdt/Patent-Marking.pdf">www.onsemi.com/site/pdt/Patent-Marking.pdf</a>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and exp

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative